Thyristor Semiconductor Device - Page 1 of 1



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Inclosure I	viateriai:
Metal	
Overall Le	-
0.210 inche	95
Terminal L	ength:
0.500 inche	95
Overall Dia	ameter:
0.230 inche	25
Internal Co	onfiguration:
Junction co	ntact
Mounting	Method:
Terminal	
	Circle Diameter:
0.100 inche	25
Features F	Provided:
Hermetical	y sealed case
Semicond	uctor Material:
Silicon	
Voltage Ra	ating In Volts Per Characteristic:
40.0 break	over voltage, dc
Current Ra	ting Per Characteristic:
175.00 mill	amperes source cutoff current preset
Maximum	Operating Tempurature Per Measurement Point:
125.0 degr	ees celsius junction
Special Fe	atures:
Junction pa	ttern arrangement: pnpn
Terminal T	ype And Quantity:
4 uninsulat	ed wire lead
Specificati	on Data:
80131-relea	ase4717 professional/industrial association specification
Shelf Life:	
N/a	
Unit Of Me	asure:
Demilitariz	ation:
No	
Fiig:	
A110a0	